

Optically induced spin polarization of an electric current through a quantum dot

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Abstract

We examine electron transport through semiconductor quantum dot subject to a continuous circularly polarized optical irradiation resonant to the electron-heavy hole transition. Electrons having certain spin polarization experience Rabi oscillation and their energy levels are shifted by the Rabi frequency. Correspondingly, the equilibrium chemical potential of the leads and the lead-to-lead bias voltage can be adjusted so only electrons with spin-up polarization or only electrons with spin-down polarization contribute to the current. The temperature dependence of the spin polarization of the current is also discussed.

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Recently, spin electronics, so-called spintronics, has become a focal point of intense research interest (see, for example, review [1] and references therein). Electronic devices employing the additional spin degree of freedom, as well as purely spin-based devices, can increase the speed of performance, consume less power, and provide novel modes of operation in comparison with conventional counterparts. Creation, control, and transmission of spin polarization constitute the principal tasks of spintronics. To polarize electron and nuclear spins, one can apply, for example, an external magnetic field (or put spin particles in contact with ferromagnetic materials) [2, 3]. Other possibilities for creation of the spin polarization include optical orientation of electron spins by a circularly polarized light [4] and polarized spin injection from the ferromagnetic/normal semiconductor junction [5].

In the present paper we propose to combine the optical spin polarization technique with electron transport through semiconductor quantum dots to produce a spin polarization of the electron current. Creating electron-hole pair with an electron having certain spin projection, we prevent the tunneling of electrons with the same spin projection to the quantum dot, breaking the spin symmetry of the current. Electron spin polarization in the dot can be achieved by the circular polarized light. In particular, the photons with the positive helicity create heavy holes with spin $3/2$ and electrons with spin $-1/2$, whereas the photons having negative helicity create heavy holes with spin $-3/2$ and electrons with spin $1/2$. For the self-assembled quantum dots (for example, InGaAs/GaAs), the lattice mismatch leads to the removal of the degeneracy between heavy and light hole energy levels, and the electron-heavy hole pairs can be created resonantly. Under resonant continuous optical irradiation, electron-hole pairs (with certain electron spin projection) exhibit Rabi oscillations [6], and the energy level for the electrons having this spin projection is shifted by $\frac{\hbar}{2} \Omega_R$, where Ω_R is the Rabi frequency. We show that in this case the conductance peaks occur not when the chemical potential of the leads is in the resonance with the energy of the quantum dot level, E_c , but when it is in the resonance with the energy $E_c - \frac{\hbar}{2} \Omega_R$ ($\hbar = 1$). However, for electrons having the spin projection which is not affected by the light, the conductance peak position remains the same. Accordingly, for appropriate values of the Rabi frequency, the equilibrium chemical potential of the leads, and the lead-to-lead voltage bias, the spin polarization of the electron current through the quantum dot can be achieved and, moreover, the direction of the polarization can be controlled by these parameters.

We examine a self-assembled InGaAs/GaAs semiconductor quantum dot which is electri-

cally coupled to two leads (similar structure was examined experimentally, for example, in Ref. [7]) and is subject to a continuous circularly polarized light having frequency resonant to the electron-heavy hole transition and negative helicity. In this case, photons create an electron-hole pairs in the dot with electrons and holes having spin projections $1/2$ and $-3/2$, respectively. Electrons with both spin projections can tunnel from the leads to the dot with spin-independent tunneling rates, whereas the hole tunneling is assumed to be suppressed.

The Hamiltonian of the system has the form

$$H = E_c (a_1^\dagger a_1 + a_2^\dagger a_2) + E_v d^\dagger d + \sum_{k; \sigma} E_k c_{k; \sigma}^\dagger c_{k; \sigma} + F(t) (a_1^\dagger d^\dagger + da_1) + \sum_{k; \sigma} (T_k c_{k; \sigma}^\dagger a + T_k a^\dagger c_{k; \sigma}); \quad (1)$$

with $\sigma = L; R$ and spin index $\sigma = 1; 2$. Operators $c_{k; \sigma}$ are related to electrons in leads, whereas $a_1; a_2$ describe an electron in the dot with spin projections $\sigma = 1; 2$ as $a_1 = a_{\sigma=1}$ and $a_2 = a_{\sigma=2}$. The holes have only one projection, so that $d = d_{\sigma=2}$. The monochromatic electromagnetic field is given by $F(t) = F e^{i\omega_0 t} + F e^{-i\omega_0 t}$. The Coulomb interaction between electrons and holes is neglected. From this Hamiltonian we derive the equations of motion for the electron/hole amplitudes as

$$i\dot{a}_1 = E_c a_1 - F(t) d^\dagger + \sum_{k; \sigma} T_k c_{k; \sigma}^\dagger; \quad (2a)$$

$$i\dot{a}_2 = E_c a_2 + \sum_{k; \sigma} T_k c_{k; \sigma}; \quad (2b)$$

$$i\dot{d}^\dagger = -E_v d^\dagger - F(t) a_1; \quad (2c)$$

and

$$i\dot{c}_{k; \sigma} = E_k c_{k; \sigma} - T_k a; \quad (2d)$$

Introducing new electron/hole variables, $A = a e^{iE_c t}$ and $D = d e^{iE_v t}$, we rewrite Eq. (2) as

$$i\dot{A}_1 = F(t) e^{i(E_c + E_v)t} D^\dagger + \sum_{k; \sigma} T_k e^{iE_c t} c_{k; \sigma}^\dagger; \quad (3a)$$

$$i\dot{A}_2 = \sum_k T_k e^{iE_c t} c_{k,2}; \quad (3b)$$

$$i\dot{D}^+ = F(t) e^{i(E_c + E_v)t} A_1; \quad (3c)$$

and

$$i\dot{c}_{k,1} = E_k c_{k,1} - T_k e^{iE_c t} A_1; \quad (3d)$$

For the resonant electromagnetic field with the frequency $\omega_0 = E_c + E_v$, the rotating wave approximation (RWA) can be applied and, accordingly, $F(t) e^{i(E_c + E_v)t} \rightarrow F_0$; $F(t) e^{i(E_c + E_v)t} \rightarrow F_0$. Correspondingly, the equation for the amplitude A_1 has the form

$$i \frac{d}{dt} A_1 = \sum_k \frac{d}{dt} T_k e^{iE_c t} c_{k,1}; \quad (4)$$

where the amplitude of the electromagnetic field, F_0 , denotes the Rabi frequency: $\Omega_R = F_0$. The response of the leads is described by the relation [8]

$$c_{k,1}(t) = c_{k,1}^{(0)}(t) - T_k \int_{t_1}^Z dt_1 g_k^r(t; t_1) e^{iE_c t_1} A_1(t_1); \quad (5)$$

where

$$g_k^r(t; t_1) = -ie^{iE_k(t-t_1)} \theta(t-t_1) \quad (6a)$$

and

$$hc_k^{(0)}(t_1) + c_k^{(0)}(t) i = f(E_k) e^{iE_k(t-t_1)} \quad (6b)$$

are the Green functions of electrons in the leads, $\theta(t-t_1)$ is the unit Heaviside function, and $f(E) = \exp \frac{E - \mu}{T} + 1^{-1}$ is the Fermi distribution with temperature T . Here, $\mu_L = \mu_R + eV = 2$ and $\mu_R = -eV = -2$; where μ is the equilibrium chemical potential of the leads and V is the voltage bias applied to the leads.

Substituting Eq. (5) into Eq. (4), we obtain

$$i \frac{d}{dt} A_1 = \sum_k \frac{d}{dt} T_k e^{iE_c t} c_{k,1} = \sum_k \frac{d}{dt} T_k e^{iE_c t} c_{k,1}^{(0)} - \sum_k T_k \int_{t_1}^Z dt_1 g_k^r(t; t_1) e^{iE_c t_1} A_1(t_1) = \sum_k \frac{d}{dt} T_k e^{iE_c t} c_{k,1}^{(0)}; \quad (7)$$

The solution of this equation can be written as

$$A_1(t) = i \frac{d}{dt} \int_{t^0}^Z dt G_1^r(t-t^0) \sum_k T_k e^{iE_c t^0} c_{k,1}^{(0)}(t^0); \quad (8)$$

where the Fourier transform of the retarded Green function $G_1^r(t-t^0)$ is given by

$$G_1^r(!) = \frac{1}{!^2 - \frac{1}{2} \sum_k \Gamma_k \int g_k^r(! + E_c)}; \quad (9)$$

with $g_k^r(!) = 1/(! - E_k) - i/(! - E_k)$: Broadenings of the electron level in the dot due to its connection to the leads is described by the damping coefficients $\Gamma_k = 2 \sum_k \Gamma_k \int g_k^r(! - E_k)$; whereas the real part of the function $g_k^r(! + E_c)$ produces insignificant corrections to the Rabi frequency Ω_R : With a notation for the average linewidth of the electron level, $\Gamma = (1/2) [\sum_L \Gamma_L + \sum_R \Gamma_R]$, we obtain the expression for the Green function $G_1^r(!)$ as

$$G_1^r(!) = \frac{1}{!^2 - \frac{1}{2} \Gamma + i!(! + E_c)}; \quad (10)$$

The electron current through the quantum dot is given by

$$I_{\uparrow} = \frac{d}{dt} \sum_k \hbar c_{k,\uparrow}^+(t) c_{k,\uparrow}(t) = i \sum_k T_k e^{iE_c t} \hbar c_{k,\uparrow}^+ A_1 + \text{h.c.}; \quad (11)$$

It should be noted that the total current has two components, I_1 with spin projection $+1/2$ and I_2 with spin projection $-1/2$. Substituting Eq.(5) into Eq. (11), we obtain

$$I_{\uparrow} = i \sum_k T_k e^{iE_c t} \hbar (c_{k,\uparrow}^{(0)})^+ A_1 + \text{h.c.} + i \sum_k \int_{t^0}^Z dt [g_k^r(t-t^0)]^+ e^{iE_c(t-t^0)} \hbar A_1(t^0)^+ A_1(t) + \text{h.c.}; \quad (12)$$

The first term in the right-hand side of Eq. (12) for the spin-up polarized current ($\sigma = \uparrow$) can be evaluated as

$$i \sum_k T_k e^{iE_c t} \hbar (c_{k,\uparrow}^{(0)})^+ A_1 + \text{h.c.} = 2 \sum_k \frac{d!}{2} (! - E_c) \text{Im} [G_1^r(! - E_c)] f(!) (1 - f(!)); \quad (13)$$

It follows from Eq.(8) that the correlator $\hbar A_1(t^0)^+ A_1(t)$ has the form ($\sigma = \uparrow, R$)

$$\hbar A_1(t^0)^+ A_1(t) = \sum_k \frac{d!}{2} e^{-i!(t-t^0)} !^2 G_1^r(!) \int_k^X (! + E_c) f(! + E_c); \quad (14)$$

and, consequently, the second term of the right-hand side of Eq. (12) for the spin-up polarized current can be written as

$$i \sum_k \int_{-\infty}^{\infty} dt [g_k^r(t; t^0)]^\dagger e^{iE_c(t-t^0)} h A_1(t^0)^\dagger A_1(t) + \text{h.c.} = \frac{d!}{2} \frac{(\Gamma - E_c)^2}{[(\Gamma - E_c)^2 + \frac{\Omega_R^2}{4}]^2} \sum_k \Gamma_1^r(\Gamma - E_c) \Gamma_1^x(\Gamma) \Gamma_1^f(\Gamma): \quad (15)$$

The total spin-up polarized current, $I_{\uparrow 1}$ is equal to the sum of the terms, Eqs. (13) and (15), and for the steady-state regime, the current carrying the spin +1=2 has the form

$$I_1 = I_{L,\uparrow 1} = I_{R,\uparrow 1} = \frac{d!}{2} \frac{(\Gamma - E_c)^2 [\Gamma_L(\Gamma) - \Gamma_R(\Gamma)]}{[(\Gamma - E_c)^2 + \frac{\Omega_R^2}{4}]^2 + [(\Gamma - E_c)(\Gamma)]^2} \Gamma_L(\Gamma) \Gamma_R(\Gamma): \quad (16)$$

The current with the spin polarization -1/2 (which is not affected by the optical irradiation) can be determined using the same procedure as

$$I_2 = \frac{d!}{2} \frac{[\Gamma_L(\Gamma) - \Gamma_R(\Gamma)]}{(\Gamma - E_c)^2 + \frac{\Omega_R^2}{4}} \Gamma_L(\Gamma) \Gamma_R(\Gamma): \quad (17)$$

Components of a zero-temperature conductance of the system, $G_{\pm 1=2} = \frac{d}{dV} (eI_{1,2})$; related to the different spin projections, exhibit the resonant behavior as functions of the equilibrium chemical potential of the leads, μ , (or the gate voltage applied to the dot) as

$$G_{+1=2} = \frac{e^2}{h} \frac{(\Gamma - E_c)^2}{[(\Gamma - E_c)^2 + \frac{\Omega_R^2}{4}]^2 + (\Gamma - E_c)^2}; \quad (18)$$

$$G_{-1=2} = \frac{e^2}{h} \frac{\Omega_R^2}{(\Gamma - E_c)^2 + \frac{\Omega_R^2}{4}}; \quad (19)$$

where we assume symmetric coupling to the leads with $\Gamma_L = \Gamma_R = \Gamma$ ($\Gamma_L = \Gamma_R$): This resonant behavior is illustrated by Figure 1 for the Rabi frequency $\Omega_R = 2$. One can see from this figure that the conductance peaks for the electrons having spin projection 1/2 (affected by the optical irradiation) are shifted from the equilibrium resonant condition ($\mu = E_c$) by Ω_R . Furthermore, it is evident that with variation such parameters as the equilibrium chemical potential of the leads, the Rabi frequency, and the lead-to-lead voltage bias, regimes with different spin polarization of the current through the quantum dot can be achieved.

To describe the spin polarization of the current and its dependence on the system parameters, we introduce the polarization coefficient as

$$P = \frac{I_1 - I_2}{I_1 + I_2}: \quad (20)$$

The lead-to-lead voltage dependencies of the total current and the polarization coefficient are shown in Figure 2 for $E_c = 5$, $\Gamma_R = 20$, and $T = 0.43$. It is evident from this figure that there are several steps in the current-voltage characteristics. The first one occurs when the chemical potential of the right lead, $\mu_R = \epsilon_V = 2$, passes through the electron level with the energy E_c and this level becomes conductive. The electrons in this level have spin projection $-1/2$ and the current is strongly polarized. The second step corresponds to the voltage at which the chemical potential of the left lead, $\mu_L = \epsilon_V + 2$, passes through the electron level with the energy $E_c + \Gamma_R$ and electrons from this level having spin projection $+1/2$ start to contribute to the current. Accordingly, current becomes only partially polarized. Finally, the third step occurs when the chemical potential of the right lead passes through the electron level with the energy $E_c - \Gamma_R$ and the spin polarization of the current is fully compensated.

The temperature dependence of the polarization coefficient is presented in Figure 3 for small applied lead-to-lead bias and two values of the equilibrium chemical potential of the leads associated with the resonances with electron levels having different spin polarization. One can see in this Figure that at temperatures comparable to the Rabi frequency, the spin polarization of the current vanishes.

Finally, we consider the conditions necessary to observe the calculated effects in experiment. If we assume the lead-dot coupling constant to be $\Gamma_R = 20$ = 400 eV , which corresponds to the excitation density of $350 \text{ kW} \cdot \text{cm}^{-2}$, and temperature used for Figure 2 is $T = 0.43$ = 100 mK .

In conclusion, we have shown that the spin polarization of the electron current through the quantum dot can be achieved, if the dot is irradiated continuously by the resonant circularly polarized light. In this case electron-hole pairs with electrons having certain spin polarization experience Rabi oscillations and the energetic level of these electrons is shifted by Γ_R . With appropriate choice of the equilibrium chemical potential of the leads and the lead-to-lead bias voltage, the current through the dot is spin-polarized and the direction of this polarization can be controlled.

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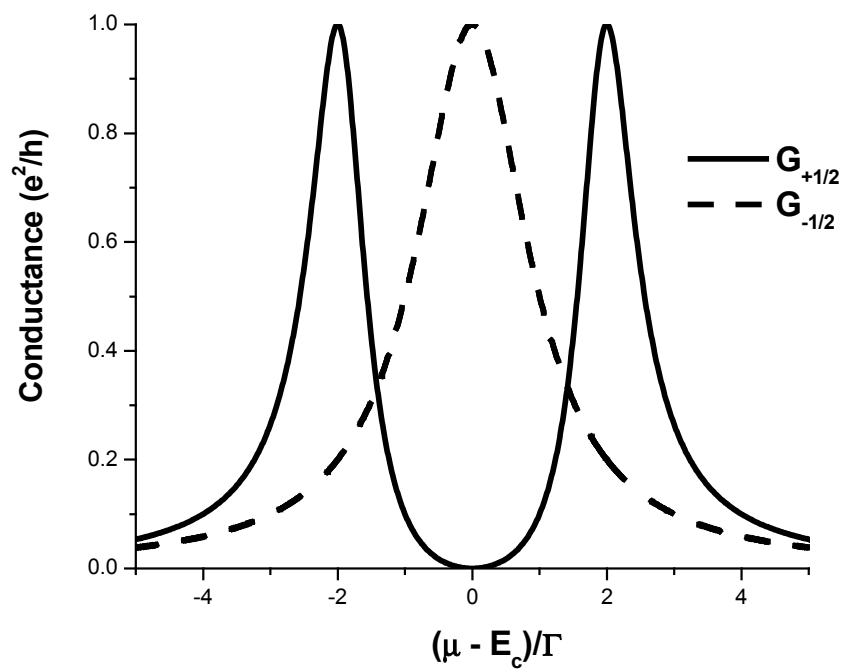
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Figures

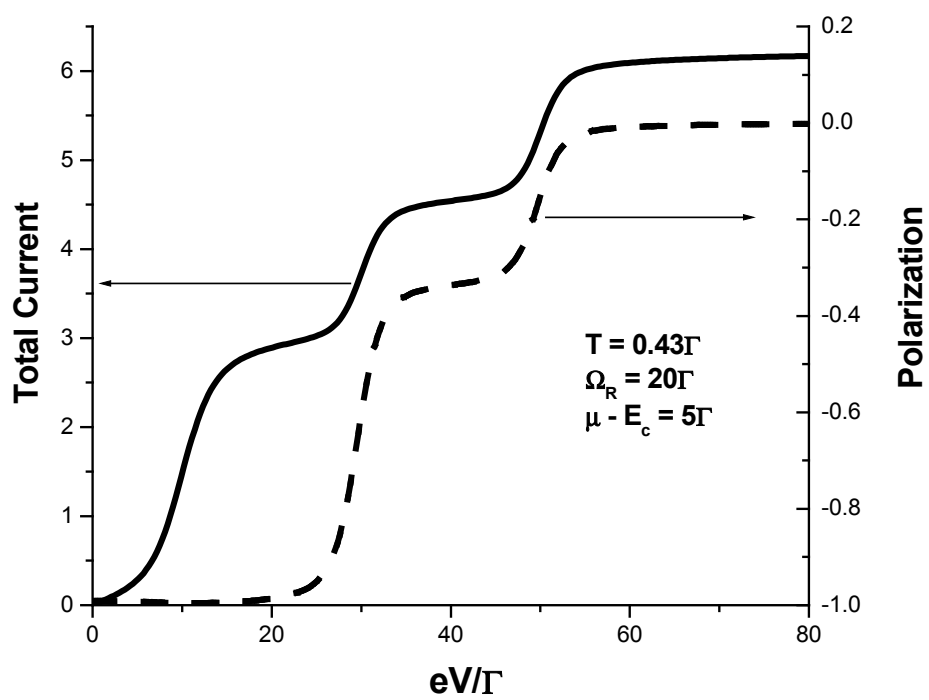
Figure 1. Zero-temperature conductances for the electrons having different spin projections as a function of the equilibrium chemical potential of the leads.

Figure 2. The total current and the current polarization as functions of the applied lead-to-lead bias.

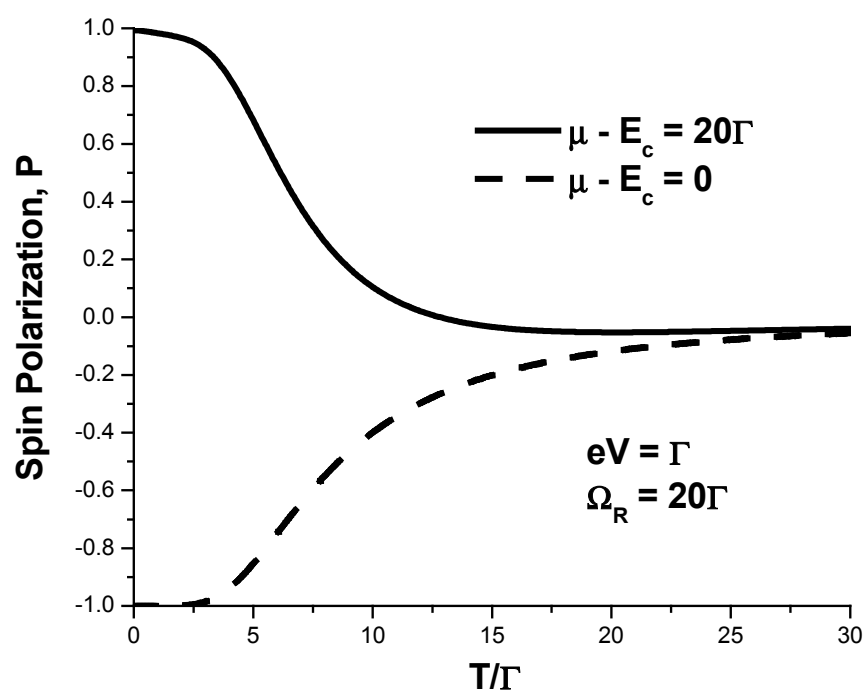
Figure 3. Temperature dependence of the current polarization.



A. Yu. Smirnov and L. G. Mourokh, Figure 1 of 4.



A. Yu. Smirnov and L. G. Mourokh, Figure 2 of 3.



A. Yu. Smirnov and L. G. Mourokh, Figure 3 of 3.

